

Photocouplers GaAlAs Infrared LED & Photo IC

TLP5754

1. Applications

- · Induction Cooktop and Home Appliances
- · Industrial Inverters
- · Air Conditioner Inverters
- · MOSFET Gate Drivers
- · IGBT Gate Drivers

General

The TLP5754 consists of a GaAlAs infrared light-emitting diode and integrated high-gain, high-speed photodetector and is house in the 6-pin SO6L package. The TLP5754 is 50 % smaller than the 8-pin DIP package and meets the reinforced insulation class requirements of international safety standards. Therefore the mounting area can be reduced in equipment requiring the safety standard certification. The TLP5754 has an internal faraday shield that provides a guaranteed common-mode transient immunity of $\pm 35~\rm kV/\mu s$. In particular, the TLP5754 has rail to rail output, and this enables stable operation and better switching performance in system.

3. Features

- (1) Buffer logic type (totem pole output)
- (2) Output peak current: ±4.0 A (max)
- (3) Operating temperature: -40 to 110°C
- (4) Supply current: 3.0 mA (max)
- (5) Supply voltage: 15 to 30 V
- (6) Threshold input current: 4 mA (max)
- (7) Propagation delay time: $t_{pHL}/t_{pLH} = 150 \text{ ns (max)}$
- (8) Common-mode transient immunity: ±35 kV/µs (min)
- (9) Isolation voltage: 5000 Vrms (min)
- (10) Safety standards

UL-approved: UL1577, File No.E67349

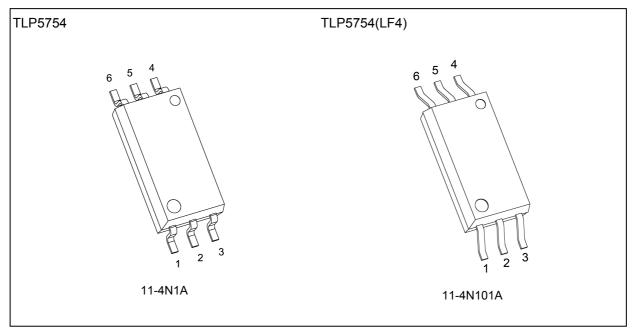
cUL-approved: CSA Component Acceptance Service No.5A File No.E67349 VDE-approved: EN60747-5-5, EN60065, EN60950-1, EN 62368-1 (Note 1)

CQC-approved: GB4943.1, GB8898 Japan and Thailand Factory

Note 1: When a VDE approved type is needed, please designate the Option (D4).

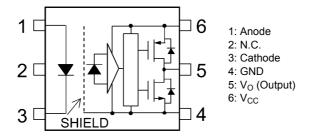


4. Packaging (Note)

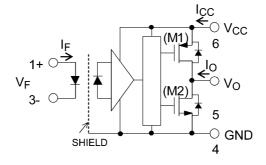


Note: Lead forming option: (LF4)

5. Pin Assignment



6. Internal Circuit (Note)



Note: A 1- μF bypass capacitor must be connected between pin 6 and pin 4.



7. Principle of Operation

7.1. Truth Table

Input	LED	M1	M2	Output
Н	ON	ON	OFF	Н
L	OFF	OFF	ON	L

7.2. Mechanical Parameters

Characteristics	Size	Unit
Height	2.3 (max)	mm
Creepage distances	8.0 (min)	
Clearance distances	8.0 (min)	
Internal isolation thickness	0.4 (min)	

8. Absolute Maximum Ratings (Note) (Unless otherwise specified, T_a = 25 °C)

	Characteristics		Symbol	Note	Rating	Unit
LED	Input forward current		I _F		20	mA
	Input forward current derating	$(T_a \ge 105 ^{\circ}C)$	$\Delta I_F/\Delta T_a$		-1	mA/°C
	Peak transient input forward current		I _{FPT}	(Note 1)	1	A
	Peak transient input forward current derating	$(T_a \ge 85 ^{\circ}C)$	$\Delta I_{FPT}/\Delta T_a$		-25	mA/°C
	Input reverse voltage		V _R		5	V
	Input power dissipation		P _D		40	mW
	Input power dissipation derating	$(T_a \ge 85 ^{\circ}C)$	$\Delta P_D/\Delta T_a$		-1.0	mW/°C
Detector	Peak high-level output current	(T _a = -40 to 110 °C)	I _{OPH}	(Note 2)	-4.0	Α
	Peak low-level output current	$(T_a = -40 \text{ to } 110 ^{\circ}\text{C})$	I _{OPL}	(Note 2)	+4.0	
	Output voltage		Vo		35	V
	Supply voltage		V _{CC}		35	
	Output power dissipation		Po		450	mW
	Output power dissipation derating	$(T_a \ge 85 ^{\circ}C)$	$\Delta P_{O}/\Delta T_{a}$		-4.5	mW/°C
Common	Operating temperature		T _{opr}		-40 to 110	°C
	Storage temperature		T _{stg}		-55 to 125	
	Lead soldering temperature	(10 s)	T _{sol}	(Note 3)	260	
	Isolation voltage	AC, 60 s, R.H. ≤ 60%	BV _S	(Note 4)	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pulse width (PW) \leq 1 μ s, 300 pps

Note 2: Exponential waveform. Pulse width \leq 2 μs , f \leq 15 kHz

Note 3: \geq 2 mm below seating plane.

Note 4: This device is considered as a two-terminal device: Pins 1, 2 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.



9. Recommended Operating Conditions (Note)

Characteristics	Symbol	Note	Min	Тур.	Max	Unit
Input on-state current	I _{F(ON)}	(Note 1)	6		15	mA
Input off-state voltage	$V_{F(OFF)}$		0		0.8	V
Supply voltage	V _{CC}	(Note 2)	15		30	
Peak high-level output current	I _{OPH}		_	_	-4.0	Α
Peak low-level output current	I _{OPL}		_	_	+4.0	
Operating frequency	f	(Note 3)		_	50	kHz

Note: The recommended operating conditions are given as a design guide necessary to obtain the intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this data sheet should also be considered.

Note: A ceramic capacitor (1 μ F) should be connected between pin 6 (V_{CC}) and pin 4 (GND) to stabilize the operation of a high-gain linear amplifier. Otherwise, this photocoupler may not switch properly. The bypass capacitor should be placed within 1 cm of each pin.

Note 1: The rise and fall times of the input on-current should be less than 0.5 μ s.

Note 2: Denotes the operating range, not the recommended operating condition.

Note 3: Exponential waveform. $I_{OPH} \ge -4.0 \text{ A} \ (\le 90 \text{ ns}), \ I_{OPL} \le 4.0 \text{ A} \ (\le 90 \text{ ns}), \ T_a = 110 \,^{\circ}\text{C}$

10. Electrical Characteristics (Note) (Unless otherwise specified, T_a = -40 to 110 °C)

Characteristics	Symbol	Note	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Input forward voltage	V _F			I _F = 10 mA, T _a = 25 °C	1.45	1.55	1.70	V
Input forward voltage temperature coefficient	$\Delta V_F/\Delta T_a$			I _F = 10 mA	_	-1.8	_	mV/°C
Input reverse current	I _R			V _R = 5 V, T _a = 25 °C	_	_	10	μА
Input capacitance	Ct			V = 0 V, f = 1 MHz, T _a = 25 °C	_	60		pF
Peak high-level output current	I _{OPH}	(Note 1)	Fig. 13.1.1	I _F = 5 mA, V _{CC} = 30 V, V ₆₋₅ = -3.5 V	_		-1.2	А
				I _F = 5 mA, V _{CC} = 15 V, V ₆₋₅ = -7 V	_		-3.0	
Peak low-level output current	I _{OPL}	(Note 1)	Fig. 13.1.2	I _F = 0 mA, V _{CC} = 30 V, V ₅₋₄ = 2.5 V	1.2	_	_	
				I _F = 0 mA, V _{CC} = 15 V, V ₅₋₄ = 7 V	3.0	_	_	
High-level output voltage	V _{OH}		Fig. 13.1.3	I _F = 4 mA, V _{CC} = 15 V, I _O = -100 mA	14.7	14.9	_	V
Low-level output voltage	V _{OL}		Fig. 13.1.4	$V_F = 0.8 \text{ V}, V_{CC} = 15 \text{ V}, I_O = 100 \text{ mA}$	_	0.07	0.2	
High-level supply current	Іссн		Fig. 13.1.5	$I_F = 10 \text{ mA}, V_{CC} = 30 \text{ V}, V_O = \text{Open}$	_	1.8	3.0	mA
Low-level supply current	I _{CCL}		Fig. 13.1.6	$I_F = 0 \text{ mA}, V_{CC} = 30 \text{ V}, V_O = \text{Open}$	_	1.7	3.0	
Threshold input current (L/H)	I _{FLH}			V _{CC} = 15 V, V _O > 1 V	_	1.4	4	
Threshold input voltage (H/L)	V _{FHL}			V _{CC} = 15 V, V _O < 1 V	0.8	_	_	V
Supply voltage	V _{CC}			_	15	_	30	
UVLO threshold voltage	V _{UVLO+}			I _F = 5 mA, V _O > 2.5 V	12.1	12.7	13.5	
	V _{UVLO-}			I _F = 5 mA, V _O < 2.5 V	11.1	11.7	12.4	
UVLO hysteresis	UVLO _{HYS}			_	_	1.0	_	

Note: All typical values are at $T_a = 25$ °C.

Note: This device is designed for low power consumption, making it more sensitive to ESD than its predecessors. Extra care should be taken in the design of circuitry and pc board implementation to avoid ESD problems.

Note 1: I_O application time $\leq 50 \mu s$; single pulse.



11. Isolation Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Note	Test Conditions	Min	Тур.	Max	Unit
Total capacitance (input to output)	Cs	(Note 1)	V _S = 0 V, f = 1 MHz		1.0		pF
Isolation resistance	R _S	(Note 1)	V_S = 500 V, R.H. \leq 60 %	1 × 10 ¹²	1014		Ω
Isolation voltage	BV _S	(Note 1)	AC, 60 s	5000	_	_	Vrms

Note 1: This device is considered as a two-terminal device: Pins 1, 2 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.

12. Switching Characteristics (Note) (Unless otherwise specified, Ta = -40 to 110 °C)

Characteristics	Symbol	Note	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Propagation delay time (L/H)	t _{pLH}	(Note 1)	Fig. 13.1.7	$I_F = 0 \rightarrow 10 \text{ mA}, V_{CC} = 30 \text{ V},$ $R_g = 10 \Omega, C_g = 25 \text{ nF}$	50		150	ns
Propagation delay time (H/L)	t _{pHL}			$I_F = 10 \rightarrow 0$ mA, $V_{CC} = 30$ V, $R_g = 10 \Omega$, $C_g = 25$ nF	50	1	150	
Rise time	t _r	(Note 1)		$I_F = 0 \rightarrow 10 \text{ mA}, V_{CC} = 30 \text{ V},$ $R_g = 10 \Omega, C_g = 25 \text{ nF}$	_	15		
Fall time	t _f	(Note 1)		$I_F = 10 \rightarrow 0$ mA, $V_{CC} = 30$ V, $R_g = 10 \Omega$, $C_g = 25$ nF	_	8	_	
Pulse width distortion	t _{pHL} -t _{pLH}	(Note 1)		$I_F = 0 \longleftrightarrow 10 \text{ mA}, V_{CC} = 30 \text{ V},$	_	_	50	
Propagation delay skew (device to device)	t _{psk}	(Note 1), (Note 2)		$R_{\rm g}$ = 10 Ω , $C_{\rm g}$ = 25 nF	-80	1	80	
High-level common-mode transient immunity	CM _H	(Note 3)	Fig. 13.1.8	$V_{CM} = 1000 V_{p-p}, I_F = 5 \text{ mA}, V_{CC} = 30 \text{ V}, T_a = 25 ^{\circ}\text{C}, V_{O(min)} = 26 \text{ V}$	±35	±40		kV/μs
Low-level common-mode transient immunity	CM _L	(Note 4)		V_{CM} = 1000 V_{p-p} , I_F = 0 mA, V_{CC} = 30 V, T_a = 25 °C, $V_{O(max)}$ = 1 V	±35	±40	_	

Note: All typical values are at $T_a = 25$ °C.

Note 1: Input signal (f = 25 kHz, duty = 50%, $t_r = t_f = 5$ ns or less).

C_L is approximately 15 pF which includes probe and stray wiring capacitance.

- Note 2: The propagation delay skew, t_{psk}, is equal to the magnitude of the worst-case difference in t_{pHL} and/or t_{pLH} that will be seen between units at the same given conditions (supply voltage, input current, temperature, etc).
- Note 3: CM_H is the maximum rate of fall of the common mode voltage that can be sustained with the output voltage in the logic high state ($V_O > 26 \text{ V}$).
- Note 4: CM_L is the maximum rate of rise of the common mode voltage that can be sustained with the output voltage in the logic low state ($V_O < 1 \text{ V}$).



13. Test Circuits and Characteristics Curves

13.1. Test Circuits

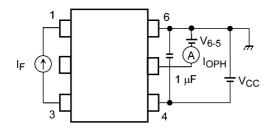


Fig. 13.1.1 I_{OPH} Test Circuit

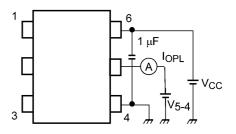


Fig. 13.1.2 I_{OPL} Test Circuit

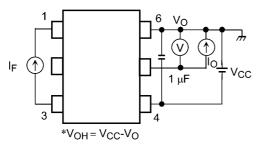


Fig. 13.1.3 V_{OH} Test Circuit

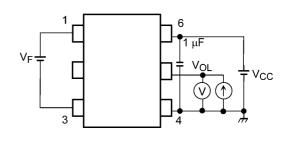


Fig. 13.1.4 V_{OL} Test Circuit

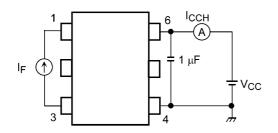


Fig. 13.1.5 I_{CCH} Test Circuit

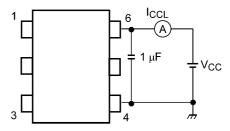


Fig. 13.1.6 I_{CCL} Test Circuit

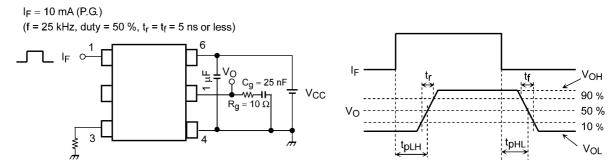


Fig. 13.1.7 Switching Time Test Circuit and Waveform



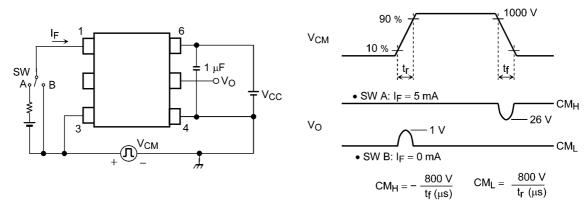


Fig. 13.1.8 Common-Mode Transient Immunity Test Circuit and Waveform



13.2. Characteristics Curves (Note)

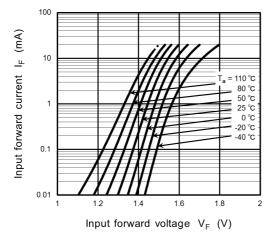


Fig. 13.2.1 I_F - V_F

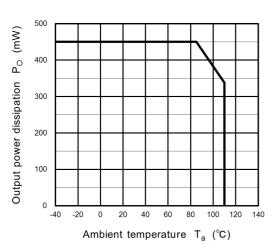


Fig. 13.2.3 Po - Ta

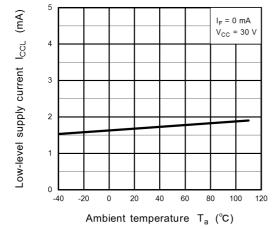


Fig. 13.2.5 I_{CCL} - T_a

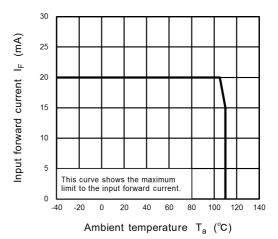


Fig. 13.2.2 I_F - T_a

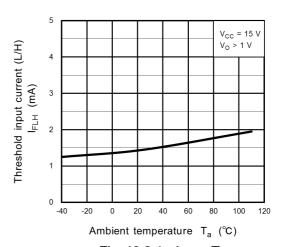


Fig. 13.2.4 I_{FLH} - T_a

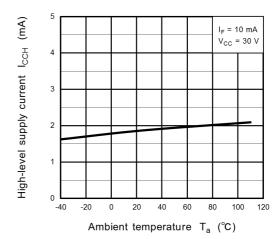


Fig. 13.2.6 I_{CCH} - T_a



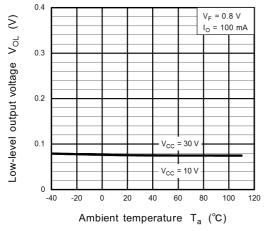


Fig. 13.2.7 V_{OL} - T_a

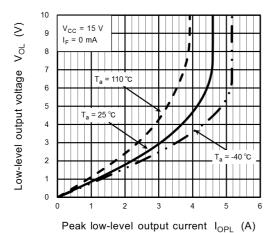


Fig. 13.2.9 V_{OL} - I_{OPL}

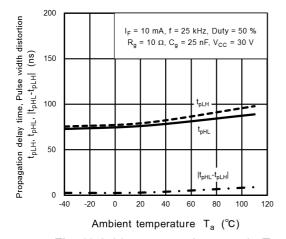


Fig. 13.2.11 t_{pLH} , t_{pHL} , $|t_{pHL}$ - $t_{pLH}|$ - T_a

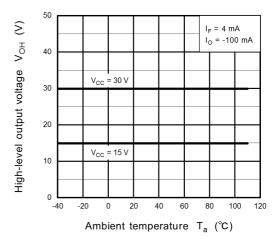


Fig. 13.2.8 V_{OH} - T_a

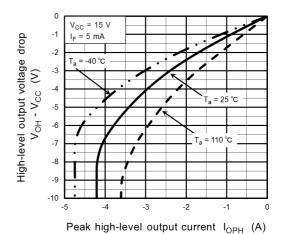


Fig. 13.2.10 (V_{OH}-V_{CC}) - I_{OPH}

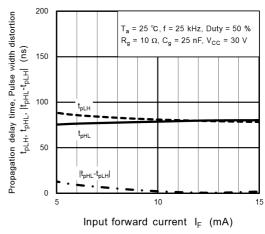


Fig. 13.2.12 $t_{pLH}, t_{pHL}, |t_{pHL}-t_{pLH}| - I_F$



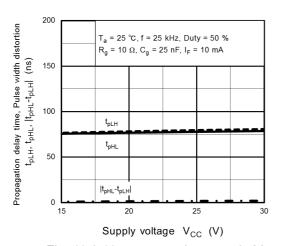


Fig. 13.2.13 $t_{pLH},t_{pHL},|t_{pHL}-t_{pLH}|-V_{CC}$

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



14. Soldering and Storage

14.1. Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

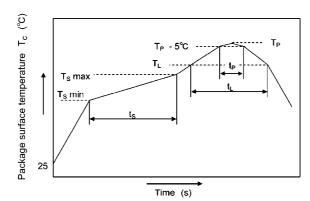
· When using soldering reflow.

The soldering temperature profile is based on the package surface temperature.

(See the figure shown below, which is based on the package surface temperature.)

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.



	Symbol	Min	Max	Unit
Preheat temperature	Ts	150	200	°C
Preheat time	ts	60	120	s
Ramp-up rate (T _L to T _P)			3	°C/s
Liquidus temperature	TL	2	°C	
Time above T _L	t _L	60	150	s
Peak temperature	T _P		260	°C
Time during which T_c is between $(T_P - 5)$ and T_P	t _P		30	s
Ramp-down rate (T _P to T _L)			6	°C/s

Fig. 14.1.1 An Example of a Temperature Profile When Lead(Pb)-Free Solder Is Used

· When using soldering flow

Preheat the device at a temperature of 150 °C (package surface temperature) for 60 to 120 seconds. Mounting condition of 260 °C within 10 seconds is recommended.

Flow soldering must be performed once.

· When using soldering Iron

Complete soldering within 10 seconds for lead temperature not exceeding 260 °C or within 3 seconds not exceeding 350 °C

Heating by soldering iron must be done only once per lead.

14.2. Precautions for General Storage

- · Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- Follow the precautions printed on the packing label of the device for transportation and storage.
- Keep the storage location temperature and humidity within a range of 5 °C to 35 °C and 45 % to 75 %, respectively.
- Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- · When restoring devices after removal from their packing, use anti-static containers.
- · Do not allow loads to be applied directly to devices while they are in storage.
- If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.



15. Land Pattern Dimensions (for reference only)

Unit: mm

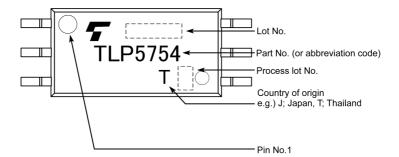
TLP5754(LF4)

TLP5754(LF4)

Fig. 15.1 Lead Forming Option (standard)

Fig. 15.2 Lead Forming Option (LF4)

16. Marking





17. EN60747-5-5 Option (D4) Specification

• Part number: TLP5754 (Note 1)

• The following part naming conventions are used for the devices that have been qualified according to option (D4) of EN60747.

Example: TLP5754(D4-TP,E

D4: EN60747 option

TP: Tape type

E: [[G]]/RoHS COMPATIBLE (Note 2)

Note 1: Use TOSHIBA standard type number for safety standard application.

e.g., TLP5754(D4-TP,E \rightarrow TLP5754

Note 2: Please contact your Toshiba sales representative for details on environmental information such as the product's RoHS compatibility.

RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Description	Symbol	Rating	Unit
Application classification			
for rated mains voltage ≤ 600 Vrms for rated mains voltage ≤ 1000 Vrms		I-IV I-III	_
Climatic classification		40 / 110 / 21	_
Pollution degree		2	_
Maximum operating insulation voltage	VIORM	1230	Vpeak
Input to output test voltage, Method A $V_{pr} = 1.6 \times \text{VIORM, type and sample test} \\ t_{p} = 10 \text{ s, partial discharge} < 5 \text{ pC}$	Vpr	1970	Vpeak
Input to output test voltage, Method B Vpr = 1.875 × VIORM, 100 % production test tp = 1 s, partial discharge < 5 pC	Vpr	2310	Vpeak
Highest permissible overvoltage (transient overvoltage, tpr = 60 s)	VTR	8000	Vpeak
Safety limiting values (max. permissible ratings in case of fault, also refer to thermal derating curve)			
current (input current IF, Pso = 0)	lsi	300	mA
power (output or total power dissipation) temperature	P _{so} T _s	700 150	mW °C
Insulation resistance V_{IO} = 500 V, T_a = 25 °C V_{IO} = 500 V, T_a = 100 °C V_{IO} = 500 V, T_a = T_s	Rsi	$ \geq 10^{12} $ $ \geq 10^{11} $ $ \geq 10^{9} $	Ω

Fig. 17.1 EN60747 Insulation Characteristics



Minimum creepage distance	Cr	8.0 mm
Minimum clearance	CI	8.0 mm
Minimum insulation thickness	ti	0.4 mm
Comparative tracking index	СТІ	175

Fig. 17.2 Insulation Related Specifications (Note)

Note: This photocoupler is suitable for safe electrical isolation only within the safety limit data.

Maintenance of the safety data shall be ensured by means of protective circuits.



Fig. 17.3 Marking on Packing for EN60747

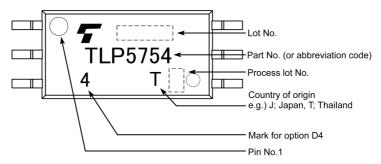
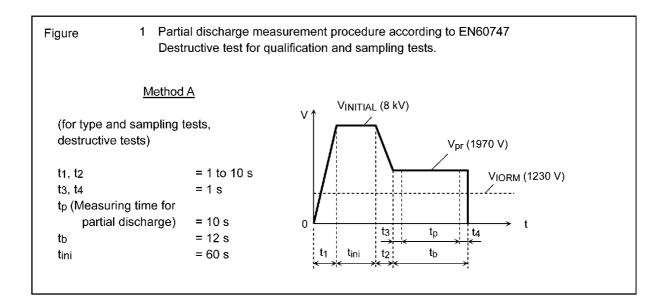
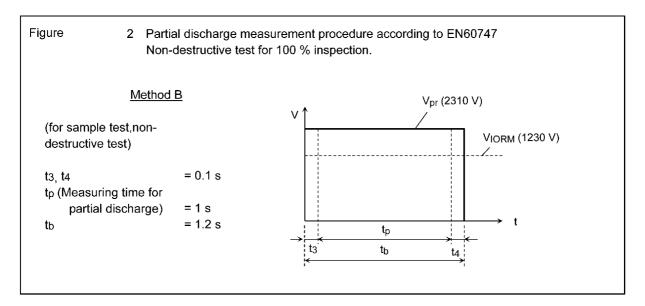


Fig. 17.4 Marking Example (Note)

Note: The above marking is applied to the photocouplers that have been qualified according to option (D4) of EN60747.







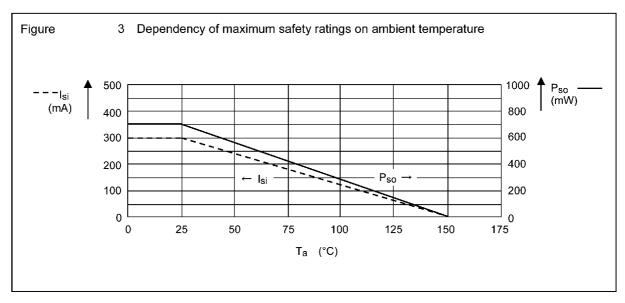


Fig. 17.5 Measurement Procedure



18. Embossed-Tape Packing (TP) Specification for Mini-Flat Photocouplers

18.1. Applicable Package

Package Name	Product Type
SO6L / SO6L(LF4)	Long creepage mini flat coupler

18.2. Product Naming Conventions

Type of package used for shipment is denoted by a symbol suffix after a part number. The method of classification is as below.

Example) TLP5754(TP,E

Part number: TLP5754

Tape type: TP

[[G]]/RoHS COMPATIBLE: E (Note 1)

Note 1: Please contact your Toshiba sales representative for details on environmental information such as the product's RoHS compatibility.

RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

18.3. Tape Dimensions Specification

Tape Type	Division	Packing Amount (A unit per reel)
TP / TP4	_	1500

18.3.1. Orientation of Device in Relation to Direction of Feed

Device orientation in the carrier cavities as shown in the following figure.

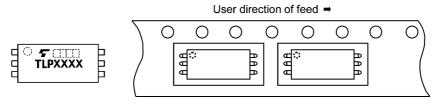


Fig. 18.3.1.1 Device Orientation

18.3.2. Empty Cavities

Characteristics	Criterion	Remarks
Occurrences of 2 or more successive empty cavities	0 device	Within any given 40-mm section of tape, not including leader and trailer
Single empty cavity	6 devices (max) per reel	Not including leader and trailer

18.3.3. Tape Leader and Trailer

The start of the tape has 14 or more empty holes. The end of the tape has 34 or more empty holes and more than 30mm only for a cover tape.



18.3.4. Tape Dimensions

Tape material: Plastic (for protection against static electricity)

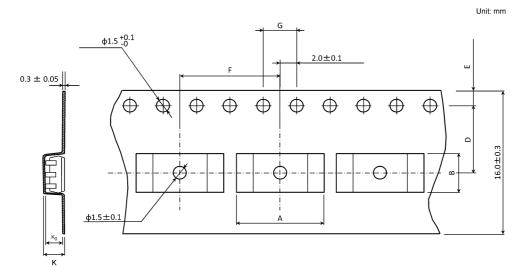


Table Tape Dimensions (unit: mm, tolerance: ±0.1)

Symbol	Dimension (standard)	Dimension (LF4)	Remark
Α	10.4	11.55	_
В	4.24	4.24	_
D	7.5	7.5	Center line of embossed cavity and sprocket hole
E	1.75	1.75	Distance between tape edge and sprocket hole center
F	12.0	16.0	Cumulative error +0.1/-0.3 per 10 empty cavities holes
G	4.0	4.0	Cumulative error +0.1/-0.3 per 10 sprocket holes
K	2.7	2.8	_
K ₀	2.4	2.4	Internal space



18.3.5. Reel Specification

Material: Plastic (for protection against static electricity)

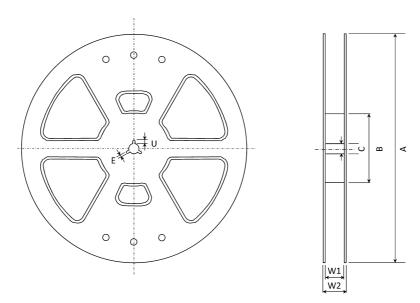
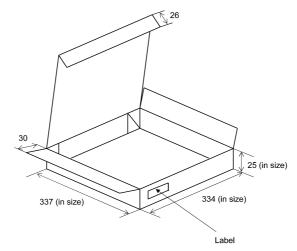


Table Reel Dimensions (unit: mm)

Symbol	Dimension
Α	φ330 ± 2
В	φ100 ± 1
С	φ13 ± 0.5
E	2.0 ± 0.5
U	4.0 ± 0.5
W1	17.4 ± 1.0
W2	21.4 ± 1.0

18.4. Packing (Note)



1 reel/carton (unit: mm)

Note: Taping reel diameter: \$\phi 330 mm

18.5. Label Format

- (1) Carton: The label provides the part number, quantity, lot number, the Toshiba logo, etc.
- (2) Reel: The label provides the part number, the taping name, quantity, lot number, etc.

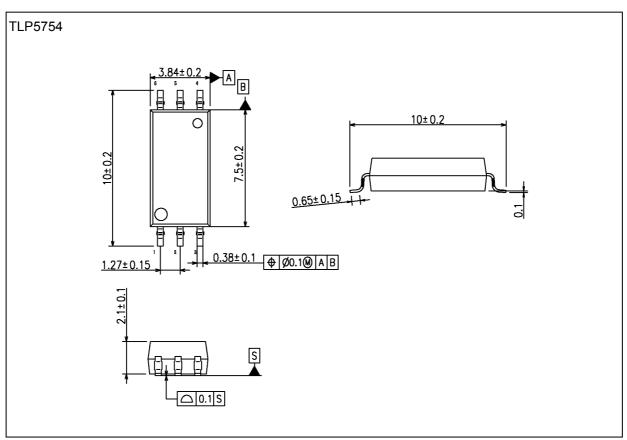


19. Ordering Information (Example of Item Name)

Item Name	Packaging	VDE Option	Packing (MOQ)
TLP5754(E			Magazine (125 pcs)
TLP5754(TP,E			Tape and reel (1500 pcs)
TLP5754(D4,E		EN60747-5-5	Magazine (125 pcs)
TLP5754(D4-TP,E		EN60747-5-5	Tape and reel (1500 pcs)
TLP5754(LF4,E	LF4, Wide forming		Magazine (125 pcs)
TLP5754(TP4,E	LF4, Wide forming		Tape and reel (1500 pcs)
TLP5754(D4-LF4,E	LF4, Wide forming	EN60747-5-5	Magazine (125 pcs)
TLP5754(D4-TP4,E	LF4, Wide forming	EN60747-5-5	Tape and reel (1500 pcs)

Package Dimensions

Unit: mm



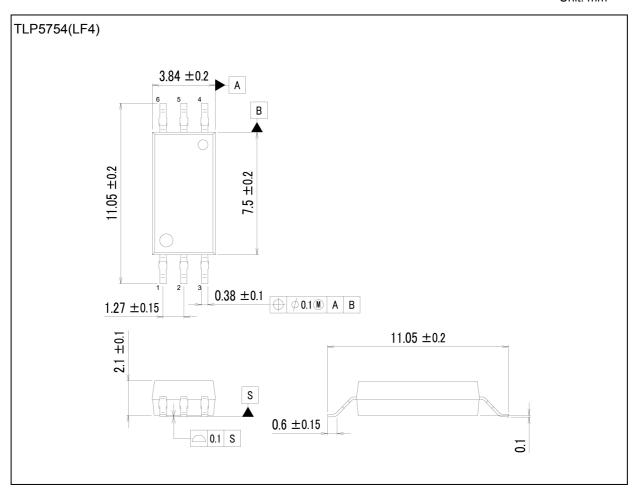
Weight: 0.126 g (typ.)

	Package Name(s)
TOSHIBA: 11-4N1A	



Package Dimensions

Unit: mm



Weight: 0.126 g (typ.)

	Package Name(s)
TOSHIBA: 11-4N101A	



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